





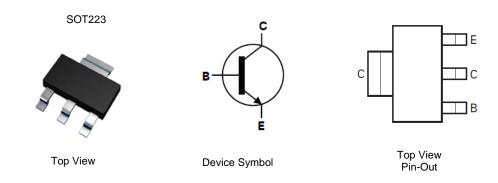
150V NPN MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > 150V
- I_C = 1A high Continuous Current
- Low Saturation Voltage
- Complementary PNP Type FZT755
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (approximate)



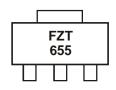
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT655TA	FZT655	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



FZT655 = Product type Marking Code





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	150	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	I _{CM}	2	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D	2	W
Power Dissipation	(Note 6)	P_{D}	3	W
Thermal Desistance Junction to Ambient	(Note 5)	0	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)	$R_{\theta JL}$	19.41	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

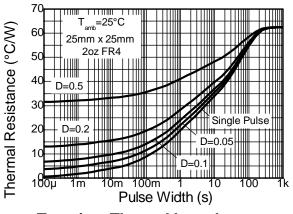
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

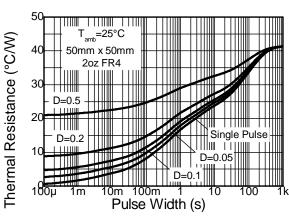
- 5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
- Same as note (5), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.
 Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



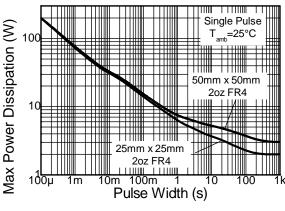
Thermal Characteristics and Derating Information



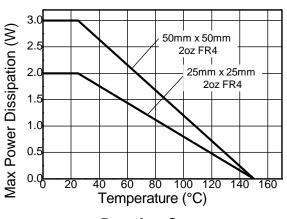
Transient Thermal Impedance



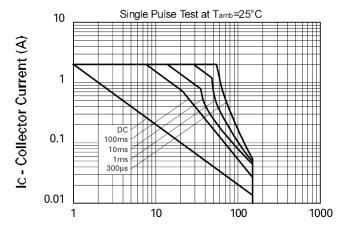
Transient Thermal Impedance



Pulse Power Dissipation



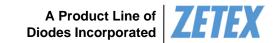
Derating Curve



VCE - Collector Emitter Voltage (V)

Safe Operating Area





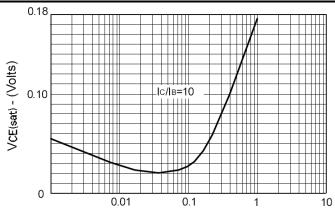
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

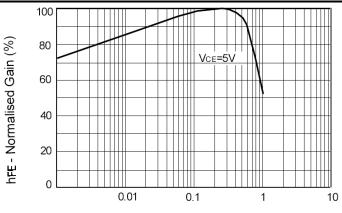
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	150	_	_	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	_	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	_	<10	100	nA	V _{CB} = 125V
Emitter Cut-off Current	I _{EBO}	_	<10	100	nA	$V_{EB} = 5.6V$
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	_	120	500	mV	I _C = 500mA, I _B = 50mA
Collector-Emitter Saturation voltage (Note 9)		_	180	500		$I_C = 1A$, $I_B = 200mA$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	0.85	1.1	V	I _C = 500mA, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	0.74	1.0	V	I _C = 500mA, V _{CE} = 5V
	hFE	50	85	_	_	$I_C = 10$ mA, $V_{CE} = 5$ V
DC Current Gain (Note 9)		50	100	300		I _C = 500mA, V _{CE} = 5V
		20	50	_		$I_C = 1A$, $V_{CE} = 5V$
Current Gain-Bandwidth Product	f⊤	30	_	-	MHz	$V_{CE} = 20V$, $I_{C} = 10mA$, $f = 20MHz$
Output Capacitance (Note 9)	C _{obo}	-	=	20	pF	V _{CB} = 10V, f = 1MHz

Notes: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%







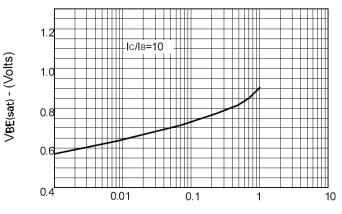


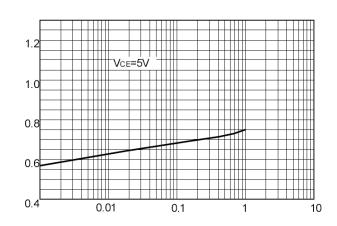
Ic - Collector Current (Amps)

Ic - Collector Current (Amps)

hFE v IC



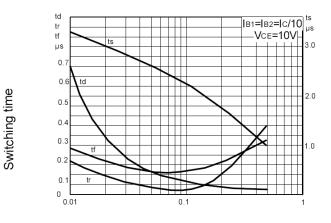




Ic - Collector Current (Amps)

Ic - Collector Current (Amps)

VBE(sat) v IC



VBE(on) v IC

Ic - Collector Current (Amps)

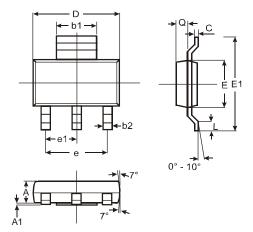
Switching Speeds

VBE - (Volts)



Package Outline Dimensions

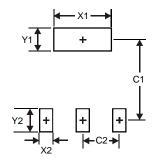
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е		_	4.60		
e1	_		2.30		
L	0.85	1.05	0.95		
ø	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
X1	3.3		
X2	1.2		
Y1	1.6		
Y2	1.6		
C1	6.4		
C2	2.3		





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